Cove-edged nanographenes as a potential opticalgain media for lasing

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Abstract

The application of zigzag- and armchairedged nanographenes (NGs) for the development of solid-state lasers has been compromised by their limited solubility and spontaneous aggregation^{[1][2]}. In this work, we study a cove-edged nanographene, hexa-peri-hexabenzo-bis-peri-octacene

(HBPO), a novel material with improved solid-state solubility due to its contorted geometry and bulky substituents. In order to characterize the optical gain, we performed Transient Absorption Spectroscopy (TAS) measurements of HBPO in solution and in a HBPO-PS thin film composite. In solution, stimulated emission (SE) is revealed by a sharp feature at 613 nm coinciding with the 0-0 vibronic PL transition. TAS measurements of the composite confirmed an enhanced performance where SE outbalances excited-state absorption, paving the way for its application as solid-state optical gain medium. This conclusion was corroborated by Amplified Spontaneous Emission (ASE) measurements, obtaining an ASE threshold

around 2.4 mJ/cm² in **HBPO**/PS films upon pumping at 465 nm. Our results are indicative of the great potential of NGs with cove edges for solid-state lighting applications.

References

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Figure 2: Input-output characteristics of ASE action and ASE threshold for the **HBPO**/PS thin film.